



## SK320 SCHOTTKY RECTIFIER

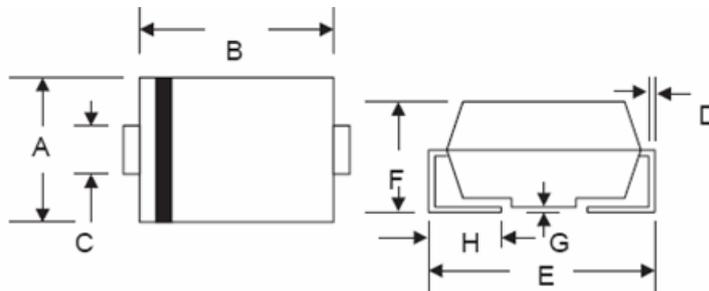
### Applications:

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

### Features:

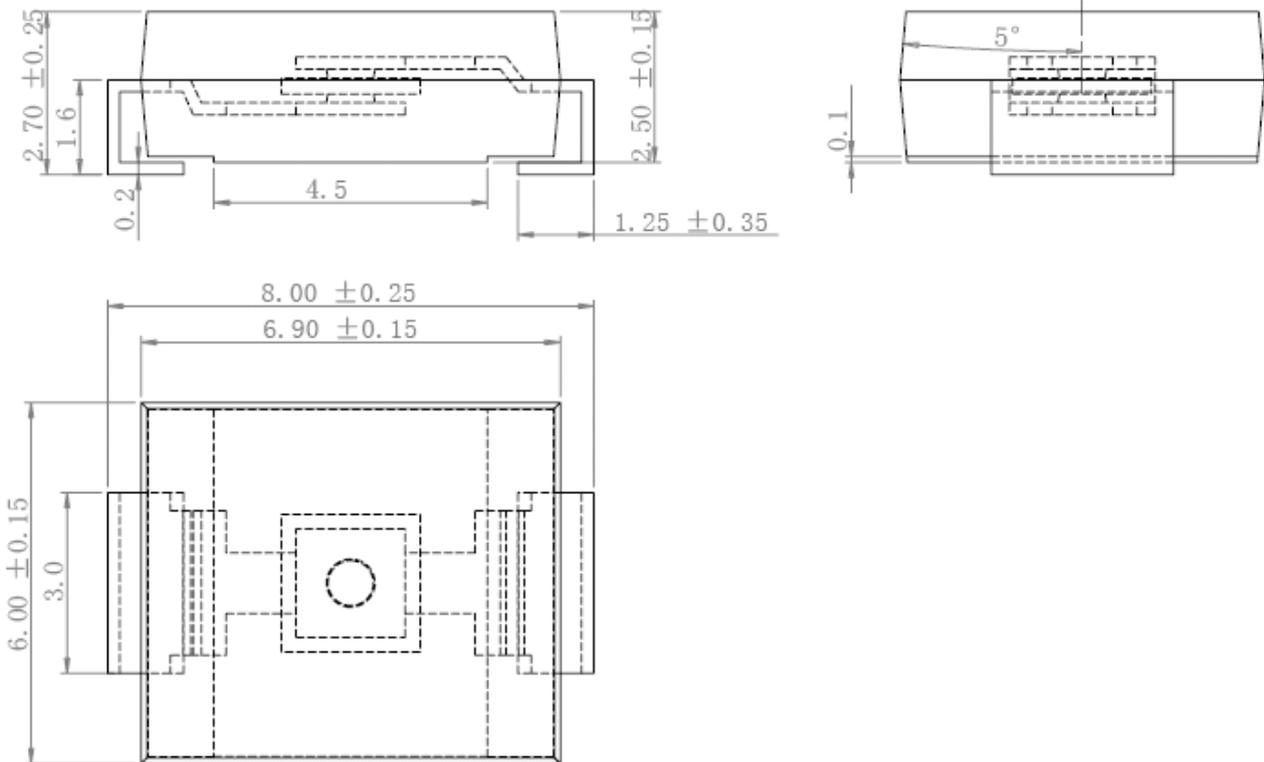
- Small foot print, surface mountable
- Very low forward Voltage Drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- Green Products in Compliance the ROHS Directive
- This is a Pb – Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

### Mechanical Dimensions (In mm)



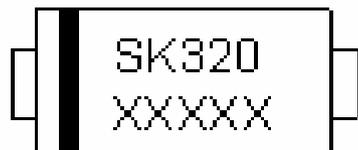
SMC/DO-214AB				
Dim	Min	Max	Min	Max
A	5.59	6.22	0.220	0.245
B	6.60	7.11	0.260	0.280
C	2.75	3.25	0.108	0.128
D	0.152	0.305	0.006	0.012
E	7.75	8.13	0.305	0.320
F	2.00	2.62	0.079	0.103
G	0.051	0.203	0.002	0.008
H	0.76	1.27	0.030	0.05
	In mm		In inch	

### OPTION 1



**OPTION 2(JK)**

**SMC**

**Marking Diagram:**


Where XXXXX is YYWWL

SK320	= Part Name
YY	= Year
WW	= Week
L	= Lot Number

**Cautions:** Molding resin  
 Epoxy resin UL:94V-0

**Ordering Information**

Device	Package	Shipping
SK320	SMC (Pb-Free)	3000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

**Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	$V_{RWM}$	-	200	V
Max. Average Forward	$I_{F(AV)}$	50% duty cycle @TC =105°C rectangular wave form(L=0.375")	3.0	A
Max. Peak One Cycle Non-Repetitive Surge Current	$I_{FSM}$	8.3 ms, half Sine pulse	110	A

**Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	$V_{F1}$	@ 3A, Pulse, $T_J = 25^\circ\text{C}$	0.90	V
	$V_{F1}$	@ 3A, Pulse, $T_J = 125^\circ\text{C}$	0.80	V
Max. Reverse Current	$I_{R1}$	@ $V_R = \text{rated VR}$ $T_J = 25^\circ\text{C}$	1.0	mA
	$I_{R2}$	@ $V_R = \text{rated VR}$ $T_J = 125^\circ\text{C}$	6.0	mA
Typical Junction Capacitance	$C_j$	@ $V_R = 4.0\text{ V}$ , $T_c = 25^\circ\text{C}$ $f_{\text{SIG}} = 1\text{MHz}$	200	pF

\* Pulse Width < 300 $\mu\text{s}$ , Duty Cycle <2%

**Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Max. Junction Temperature	$T_J$	-	-55 to +150	$^\circ\text{C}$
Max. Storage Temperature	$T_{\text{stg}}$	-	-55 to +150	$^\circ\text{C}$
Maximum Thermal Resistance Junction to Lead	$R_{\theta\text{JL}}$	DC operation	12	$^\circ\text{C/W}$
Maximum Thermal Resistance, Case to Heat Sink	$R_{\theta\text{JA}}$	DC operation	111	$^\circ\text{C/W}$
Approximate Weight	wt	-	0.65	g
Case Style	SMC			

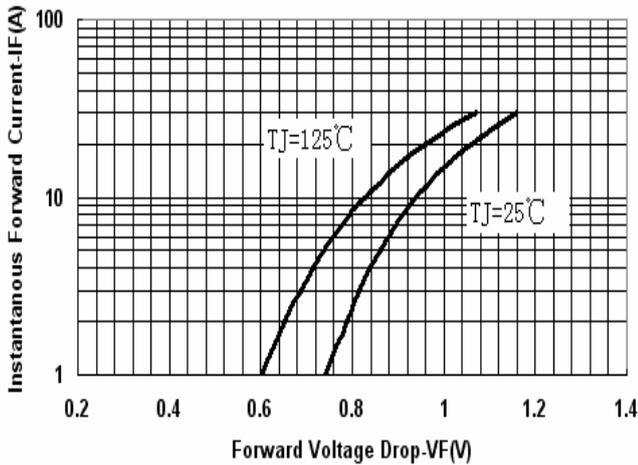


Fig.1-Typical Forward Voltage Drop Characteristics

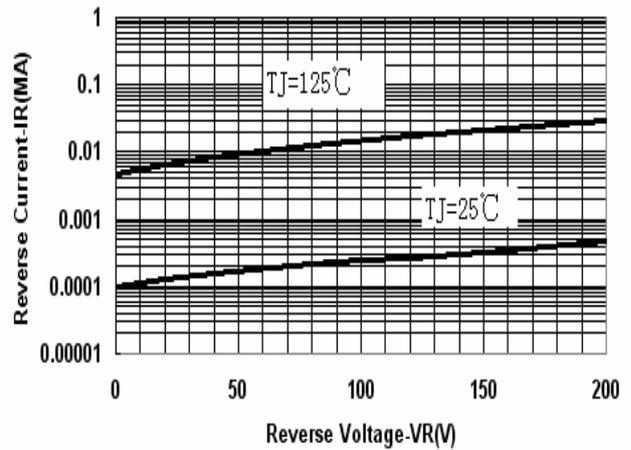


Fig.2-Typical Values Of Reverse Current Vs.Reverse Voltage

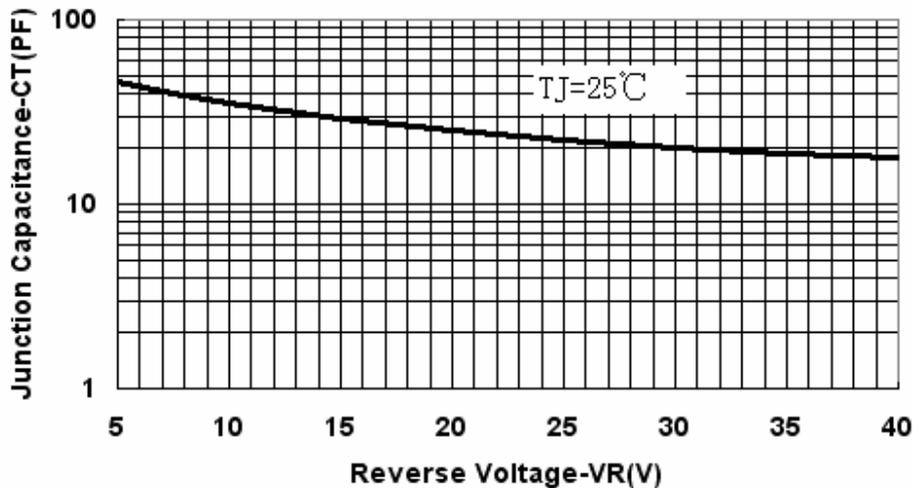


Fig.3-Typical Junction Capacitance Vs.Reverse Voltage

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